



#### N-CHANNEL ENHANCEMENT MODE MOSFET

## **Features**

- Low On-Resistance:
  - 3.0 Ω @ 4.5V
  - 4.0 Ω @ 2.5V
  - 6.0 Ω @ 1.8V
  - 10 Ω @ 1.5V
- Very Low Gate Threshold Voltage, 1.0V max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected Gate
- Lead, Halogen, and Antimony Free By Design/RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

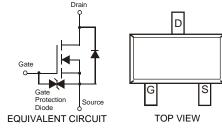
### **Mechanical Data**

- Case: SOT-523
- Case Material: Molded Plastic, "Green" Molding Compound. UL • Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.002 grams (approximate)





TOP VIEW



## **Maximum Ratings** $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V <sub>DSS</sub>	20	V
Gate-Source Voltage	V <sub>GSS</sub>	±10	V
Drain Current (Note 1)	ID	230	mA
Pulsed Drain Current T <sub>P</sub> =	10µs I <sub>DM</sub>	805	mA

## Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Total Power Dissipation (Note 1)	PD	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	R <sub>0</sub> JA	417	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added lead.

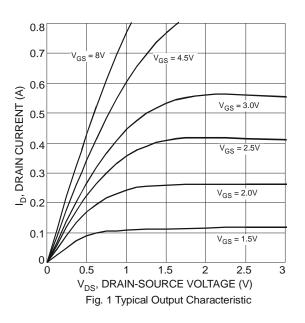
3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

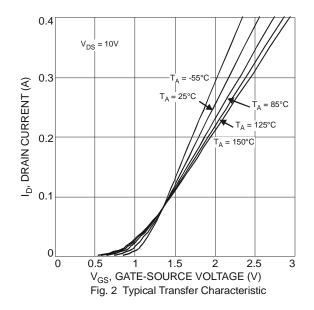


## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic			Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 4)					l	l		
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	20	_	_	V	$V_{GS} = 0V, I_D = 100 \mu A$	
Zero Gate Voltage Drain Current	@ T <sub>C</sub> = 25°C	IDSS	_		500	nA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Body Leakage			_	_	±1 ±500 ±100	μA nA nA	$V_{GS} = \pm 10V, V_{DS} = 0V$ $V_{GS} = \pm 8V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 4)					•	•		
Gate Threshold Voltage		V <sub>GS(th)</sub>	0.5		1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance			 	1.8 2.4 2.9 3.7 5.4	3.0 4.0 6.0 10.0 15.0	Ω	$V_{GS} = 4.5V, I_D = 100mA$ $V_{GS} = 2.5V, I_D = 50mA$ $V_{GS} = 1.8V, I_D = 20mA$ $V_{GS} = 1.5V, I_D = 10mA$ $V_{GS} = 1.2V, I_D = 1mA$	
Forward Transconductance			_	242	_	mS	$V_{DS} = 10V, I_D = 0.1A$	
Source-Drain Diode Forward Voltage			0.5		1.0	V	$V_{GS} = 0V, I_{S} = 115mA$	
DYNAMIC CHARACTERISTICS								
Input Capacitance		Ciss	—	14.1		pF		
Output Capacitance		Coss		2.9		pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V f = 1.0MHz	
Reverse Transfer Capacitance			_	1.6		pF	T = 1.010112	
SWITCHING CHARACTERISTICS, V <sub>GS</sub> = 4	4.5V (Note 5)							
Turn-On Delay Time	t <sub>d(on)</sub>		3.8	—				
Rise Time		tr		7.9	—	ns	$V_{GS} = 4.5V, V_{DD} = 10V$	
Turn-Off Delay Time		t <sub>d(off)</sub>		13.4	—	115	$I_D = 200 mA, R_G = 2.0 \Omega$	
Fall Time		t <sub>f</sub>	_	15.2	_			

Short duration pulse test used to minimize self-heating effect.
Switching characteristics are independent of operating junction temperature.



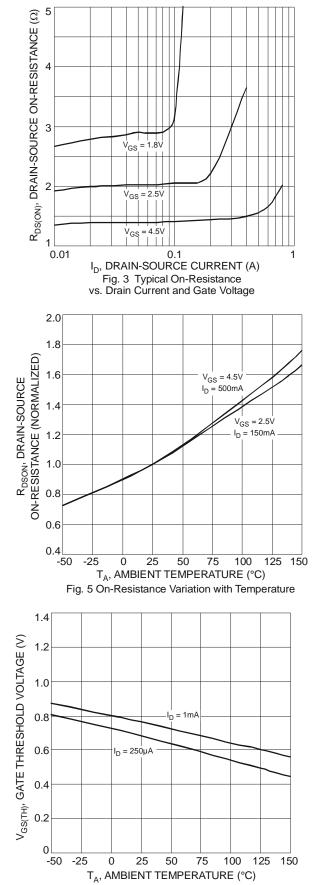


DMN26D0UT Document number: DS31854 Rev. 2 - 2

Notes:



## DMN26D0UT





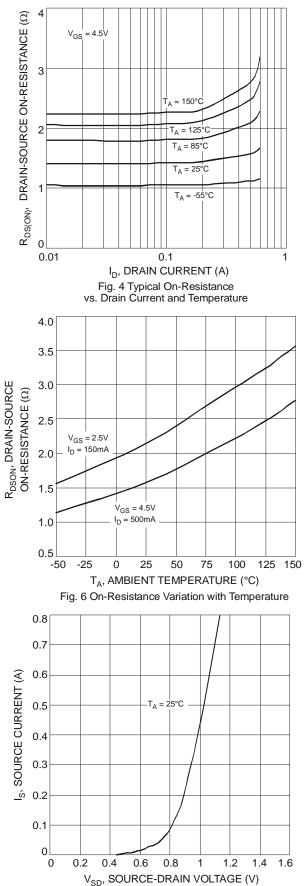
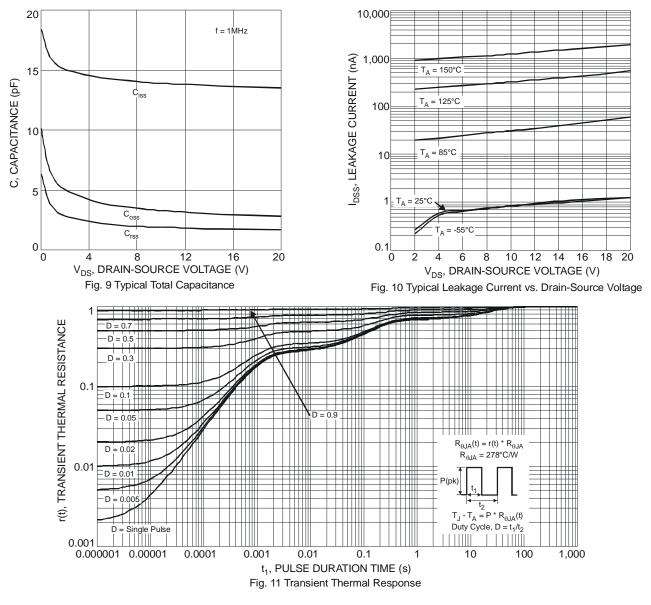


Fig. 8 Diode Forward Voltage vs. Current



## DMN26D0UT

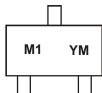


## Ordering Information (Note 6)

Part Number	Case	Packaging
DMN26D0UT-7	SOT-523	3,000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



M1 = Product Type Marking Code YM = Date Code Marking Y = Y ear (ex: W = 2009)

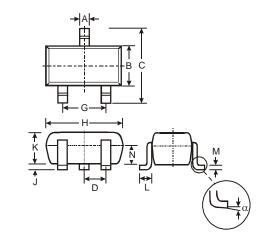
M = Month (ex: 9 = September)

Date	Code	Kev
Duio	oouo	1.09

Date Code Key												
Year	2009	9	2010		2011	20	12	2013		2014	2	2015
Code	W		Х		Y	Z	7	А		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D

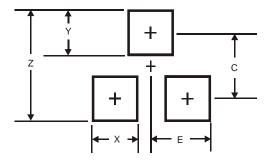


## Package Outline Dimensions



Dim	Min	N/	
		Max	Тур
Α	0.15	0.30	0.22
В	0.75	0.85	0.80
С	1.45	1.75	1.60
D	_		0.50
G	0.90	1.10	1.00
Н	1.50	1.70	1.60
J	0.00	0.10	0.05
κ	0.60	0.80	0.75
L	0.10	0.30	0.22
М	0.10	0.20	0.12
Ν	0.45	0.65	0.50
α	0°	8°	
All [	Dimensi	ions in	mm

## Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.8
Х	0.4
Y	0.51
С	1.3
E	0.7



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